

First Named Inventor	Kirk D. Prall	SECOND SUPPLEMENTAL INFORMATION DISCLOSURE STATEMENT FORM PTO-1449
Serial No.	10/786,765	
Filing Date	February 25, 2004	
Group Art Unit	2818 2814	
Examiner Name	Unknown HOAI PHAM	
Confirmation No.	2857	
Attorney Docket No.	400.266US01	
Title: MULTI-LAYER MEMORY ARRAYS		Sheet 1 of 1

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Examiner Initials	Author, Title, Date, Pages, etc.

Examiner Signature	<i>Waylan</i>	Date Considered	01/05/06
*Examiner: Initial if citation considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.			

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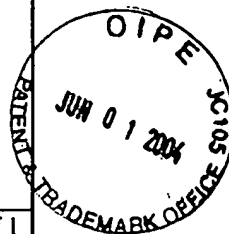
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Examiner Signature	<i>Hoaylann</i>	Date Considered	01/05/06
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